NSN 5961-01-295-3385

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-295-3385 **Inclosure Material:** Metal **Overall Length:** 1.563 inches **Overall Height:** 0.350 inches **Overall Width:** 0.820 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204ae **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 4.0 gate to source threshold voltage **Current Rating Per Characteristic:** 25.00 amperes zero-gate-voltage drain current **Power Rating Per Characteristic:** 150.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**